

STPSC1006D

600 V power Schottky silicon carbide diode

Features

- No or negligible reverse recovery
- Switching behavior independent of temperature
- Particularly suitable in PFC boost diode function

Description

The SiC diode is an ultrahigh performance power Schottky diode. It is manufactured using a silicon carbide substrate. The wide bandgap material allows the design of a Schottky diode structure with a 600 V rating. Due to the Schottky construction no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

ST SiC diodes will boost the performance of PFC operations in hard switching conditions.

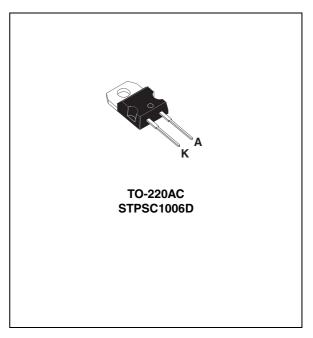


Table 1. Device summary

I _{F(AV)}	10 A
V_{RRM}	600 V
T _{j (max)}	175 °C
Q _{C (typ)}	12 nC

Characteristics STPSC1006D

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C unless otherwise specified)

Symbol	Paramete	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	600	V	
I _{F(RMS)}	RMS forward current	18	Α	
I _F	Continuous forward current	T _C = 115 °C	10	Α
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	40	Α
I _{FRM}	Repetitive peak forward current	δ = 0.1, T _C = 110 °C, T _j = 150 °C	40	Α
T _{stg}	Storage temperature range		-55 to +175	°C
Tj	Operating junction temperature	-40 to +175	°C	

Table 3. Thermal resistance

	Symbol	Parameter	Value	Unit
ĺ	R _{th(j-c)}	Junction to case	2	°C/W

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	Reverse leakage	T _j = 25 °C	V - V		30	300	^
'R ' current	T _j = 150 °C	$V_R = V_{RRM}$		210	1500	μΑ	
V (2)	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 10 A		1.4	1.7	V
v _F (-/		T _j = 150 °C	1F - 10 A		1.6	2.1	v

^{1.} $t_p = 10 \text{ ms}, \delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 1.2 \text{ x I}_{F(AV)} + 0.09 \text{ x I}_{F^2(RMS)}$

Table 5. Other parameters

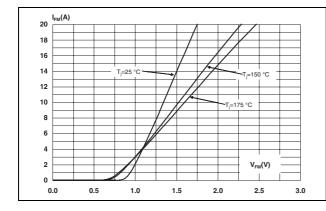
Symbol	Parameter	Test conditions	Тур	Unit
Q _c	Total capacitive charge	$V_r = 400 \text{ V}, I_F = 10 \text{ A} \text{ d}I_F/\text{d}t = -200 \text{ A}/\mu\text{s}$ $T_j = 150 ^{\circ}\text{C}$	12	nC
С	Total capacitance	$V_r = 0 \text{ V}, T_c = 25 \text{ °C}, F = 1 \text{ Mhz}$	650	pF

^{2.} $t_p = 500 \ \mu s, \ \delta < 2\%$

STPSC1006D Characteristics

Figure 1. Forward voltage drop versus forward current (typical values)

Figure 2. Reverse leakage current versus reverse voltage applied (maximum values)



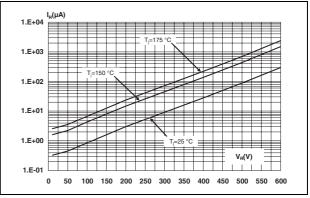
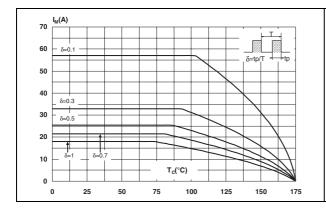
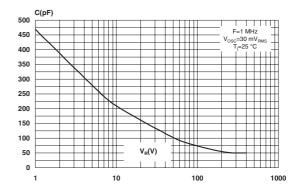


Figure 3. Peak forward current versus case temperature

Figure 4. Junction capacitance versus reverse voltage applied (typical values)

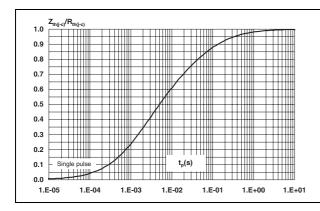




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Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

Figure 6. Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform, typical values)



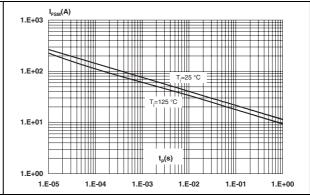
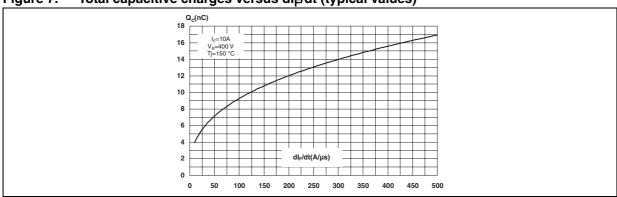


Figure 7. Total capacitive charges versus dl_F/dt (typical values)



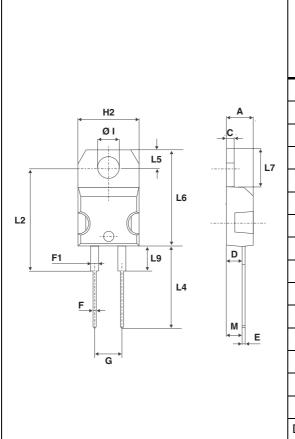
STPSC1006D Package information

2 Package information

- Epoxy meets UL94, V0
- Cooling method: C
- Recommended torque value: 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at www.st.com.

Table 6. TO-220AC Dimensions



	Dimensions				
Ref.	Millimeters		Inches		
	Min. Max.		Min.	Max.	
Α	4.40	4.60	0.173	0.181	
С	1.23	1.32	0.048	0.051	
D	2.40	2.72	0.094	0.107	
E	0.49	0.70	0.019	0.027	
F	0.61	0.88	0.024	0.034	
F1	1.14	1.70	0.044	0.066	
G	4.95	5.15	0.194	0.202	
H2	10.00	10.40	0.393	0.409	
L2	16.40 typ.		0.645 typ.		
L4	13.00	14.00	0.511	0.551	
L5	2.65	2.95	0.104	0.116	
L6	15.25	15.75	0.600	0.620	
L7	6.20	6.60	0.244	0.259	
L9	3.50	3.93	0.137	0.154	
М	2.6 typ.		0.102 typ.		
Diam. I	3.75	3.85	0.147	0.151	

Ordering information STPSC1006D

3 Ordering information

 Table 7.
 Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPSC1006D	STPSC1006D	TO-220AC	1.86 g	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Description of changes
05-May-2008	1	First issue

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